APPLICA	ABLE STA	NUARD									
	Operating Temperatu	ure Range	$\sqrt{3}$ -55°C to 85°C (No	Storage Temperature Ran		е	−10°C TO 60	°C			
RATING	Voltage		∆ 50V AC/DC						_		
	Current	_	Signal contact : 0.3A			_			_	-	
			Power contact : 2.0A		ATIONS						
	TEM		TEST METHOD	110	110143		EOLUBE	MENTS	QT	AT	
	TEM RUCTION		1E31 METHOD			K	EQUIRE	INIENTS	QI	ΑI	
General Examination		Visually and by measuring instrument.			Accord	According to drawing.				Х	
Marking		Confirmed visually.				According to drawing.				X	
										I .	
ELECTR	IC CHAR	ACTERIS	STICS								
Contact Resistance		20mV AC or less 1kHz,1m A .				Signal contact resistance: $50 \text{ m}\Omega \text{ MAX}$. Power contact resistance: $20 \text{ m}\Omega \text{ MAX}$.				_	
Insulation Resistance		100V DC.			1000 N	1000 MΩ MIN.				_	
Voltage Proof		150V AC 1	150V AC for 1 min.			No flashover or breakdown.				_	
		-			1				·		
MECHA	NICAL CH	IARACTE	RISTICS								
Mechanical	Operation	30times insertions and extractions. 3			Pov	 Signal contact resistance: 50 mΩ MAX. Power contact resistance: 20 mΩ MAX. No damage, crack or looseness of parts. 				_	
Vibration		Frequency 10 to 55 Hz,approx 5min, Single amplitude 0.75 mm,10cycles, for 3 directions.				 No electrical discontinuity of 1 μs. No damage, crack or Looseness of parts. 				_	
Shock		490 m/s ² duration of pulse 11 ms at 3 times			① No electrical discontinuity of 1 μs.				Х		
SHOCK		for 3 direc	tions.		② No	② No damage, crack or looseness of parts.				_	
	***********	· CHAD	ACTEDISTICS								
ENVIRO	NIVIENTA		ACTERISTICS ure -55 → +85°C		l① Sic	nal contac	t resista	nce: 50 m Ω MAX. $\sqrt{2}$	T	Π_	
Rapid Chan		Time	30 → 30 min		Po	wer contac	t resistar	nce: $20 \text{ m}\Omega \text{ MAX.}^{23}$	X		
Temperature			Under 5 cycles. (Relocation time to chanber : within 2-3 min)			② Insulation resistance: 1000MΩ MIN.③ No damage, crack or looseness of parts.				-	
Damp Heat (Steady state)		Exposed a	Exposed at 40 ± 2 °C, 90 to 95 %, 96 h.			 Signal contact resistance: 50 mΩ MAX. Power contact resistance: 20 mΩ MAX. Insulation resistance: 100MΩ MIN. No damage, crack or looseness of parts. 				_	
			Exposed in 25 PPM for 96h,25°C,75%. (Refer to JIS C 60068)			Signal contact resistance: $50 \text{ m}\Omega \text{ MAX}$. Power contact resistance: $20 \text{ m}\Omega \text{ MAX}$.					
		•			ļ				•		
COUN	NT [DESCRIPTIO	ESCRIPTION OF REVISIONS		DESIGNED		CHECKED		DA	TE	
<u>√</u> 3 8		DIS-H	H-00019811	RT. SHIMIZU		<u>, </u>		TY. 00 I		0122	
REMARKS Note1: Include	e the temperatu	re rising by cu	rising by current			APPRO		TY. 00I		0818	
						CHECK		RT. SHIMIZU RT. OSAKI	2023	081 / 0817	
Unless otherwise specified, refer t			o JIS C 5402 and IEC 60512.			DRAW		RT. OSAKI	2023		
Note QT:Qualification Test AT:Assu			urance Test X:Applicable Test		DRAWI	DRAWING NO.		ELC-394481-53-00			
HS.	5	SPECIFICATION SHEET			PART NO.	RT NO. BM29B-12DP/2-0. 35V		-12DP/2-0. 35V (5	3)		
117	HII	HIROSE ELECTRIC CO., LTD.			CODE NO.	CL	CL0673-7081-0-53				